DIOTEC ELECTRONICS CORP.

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Data Sheet No. BRDB-800-1C ABDB-800-1C

SERIES DB800-DB810 and ADB804-ADB808

8 AMP SILICON BRIDGE RECTIFIERS

FEATURES

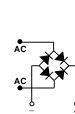
- VOID FREE VACUUM DIE SOLDERING FOR MAXIMUM MECHANICAL STRENGTH AND HEAT DISSIPATION (Solder Voids: Typical < 2%, Max. < 10% of Die Area)
- **BUILT-IN STRESS RELIEF MECHANISM FOR** SUPERIOR RELIABILITY AND PERFORMANCE
- SURGE OVERLOAD RATING TO 300 AMPS PEAK
- RECOGNIZED FILE #E124962

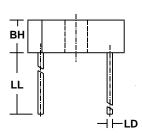
MECHANICAL DATA

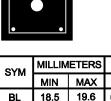
- Case: Molded plastic, U/L Flammability Rating 94V-0
- Terminals: Round silver plated copper pins
- Soldering: Per MIL-STD 202 Method 208 guaranteed
- . Polarity: Marked on side of case; positive lead at beveled corner
- Mounting Position: Any. Through hole provided for #6 screw
- Weight: 0.18 Ounces (5.4 Grams)

MECHANICAL SPECIFICATION

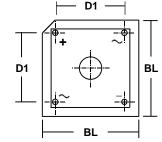








SYM	MILLIM	IETERS	INCHES						
	MIN	MAX	MIN	MAX					
BL	18.5	19.6	0.73	0.77					
ВН	6.4	7.6	0.25	0.3					
D1	12.2	13.2	0.48	0.52					
LL	22.2	n/a	0.875	n/a					
LD	1.2	1.3	0.048	0.052					



MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 $^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%.

PARAMETER (TEST CONDITIONS)		RATINGS CONTROLLED NON-CONTROLLED										
		CONTROLLED NON-CONTRO AVALANCHE AVALANC						:D		UNITS		
Series Number		ADB 804	ADB 806	ADB 808	DB 800	DB 801	DB 802	DB 804	DB 806	DB 808	DB 810	
Maximum DC Blocking Voltage												
Working Peak Reverse Voltage	Vrwm	400	600	800	50	100	200	400	600	800	1000	VOLTS
Maximum Peak Recurrent Reverse Voltage	VRRM											
RMS Reverse Voltage		280	420	560	35	70	140	280	420	560	700	
Power Dissipation in V(BR) Region for 100 μS Square Wave		400 n/a										
Continuous Power Dissipation in V(BR) Region @ Ths=80° C (Heat Sink Temp)	PR	2			n/a							WATTS
Thermal Energy (Rating for Fusing)		64								AMPS ² SEC		
Peak Forward Surge Current. Single 60Hz Half-Sine Wave Superimposed on Rated Load (JEDEC Method). TJ = 150° C		300								AMPS		
Average Forward Rectified Current @ Tc = 50° C (Note 1) @TA = 50° C (Note 2)	lo	10 8								Aimi		
Junction Operating and Storage Temperature Range		-55 to +150								°C		
Minimum Avalanche Voltage		See Note 4				n/a						
Maximum Avalanche Voltage		See Note 4			n/a							VOLTS
Maximum Forward Voltage (Per Diode) at 4 Amps DC		0.95 (Typ. 0.90)										
Maximum Reverse Current at Rated V _{RM} @ T _A = 25° C @T _A = 125° C		1 50								μ Α		
Minimum Insulation Breakdown Voltage (Circuit to Case)		2000								VOLTS		
Typical Thermal Resistance Junction to Ambient (Note 2) Junction to Case (Note 1)		12 5								°C/W		

NOTES: (1) Bridge mounted on 4.9" x 4.3" x 0.11" thick (12.4cm x 10.8cm x 0.3cm) aluminum plate

Downloaded from Elcodis.com electronic components distributor

(2) Bridge mounted on PC Board with 0.5" sq. (12mm sq.) copper pads and bridge lead length of 0.375" (9.5mm)

(3) Bolt bridge on heat sink, using silicon thermal compound between bridge and mounting surface, for maximum heat transfer

(4) These bridges exhibit the avalanche characteristic at breakdown. If your application requires a specific breakdown voltage range, please contact us.

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8 AMP SILICON BRIDGE RECTIFIERS

RATING & CHARACTERISTIC CURVES FOR SERIES DB800 - DB810 and SERIES ADB804 - ADB808

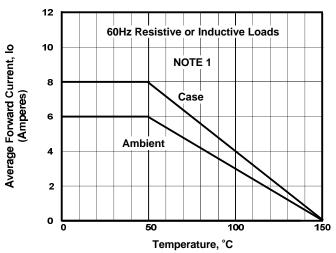
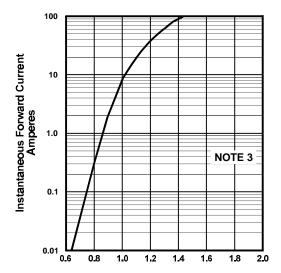


FIGURE 1. FORWARD CURRENT DERATING CURVE



Instantaneous Forward Voltage (Volts)
FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE

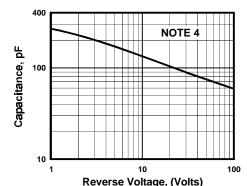


FIGURE 5. TYPICAL JUNCTION CAPACITANCE PER DIODE

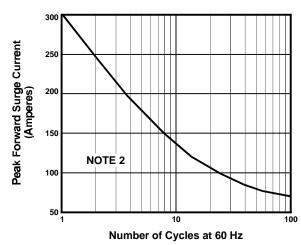
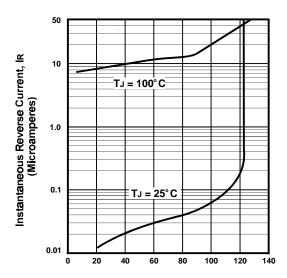


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT



Percent of Rated Peak Reverse Voltage
FIGURE 4. TYPICAL REVERSE CHARACTERISTICS

NOTES

(1) Case Temperature, Tc, With Bridge Mounted on 4.9" x 4.3" x 0.11" Thick (12.4cm x 10.8cm x 0.3cm) Aluminum Plate

Ambient Temperature, TA, With Bridge Mounted on PC Board With 0.5" Sq. (12mm Sq.) Copper Pads And Bridge Lead Length of 0.375" (9.5mm)

- (2) $T_J = 150^{\circ} C$
- (3) T_J = 25°C; Pulse Width = 300 μ Sec; 1% Duty Cycle
- (4) $T_J = 25^{\circ} C$; f = 1 MHz; Vsig = 50 mVp-p